

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shunpei Yamazaki et al.                      Art Unit : Unknown  
Serial No. : New Application                              Examiner : Unknown  
Filed : March 26, 2002  
Title : SEMICONDUCTOR DEVICE AND FABRICATION METHOD THEREOF

Commissioner for Patents  
Washington, D.C. 20231

**TRANSMITTAL OF PRIORITY DOCUMENT UNDER 35 USC §119**

Applicants hereby confirm their claim of priority under 35 USC §119 from the following application:

**Japan Application No. 2001-091275 filed March 27, 2001**

A certified copy of the application from which priority is claimed is submitted herewith.

Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: March 26, 2002

  
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日本国特許庁  
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別紙添付の書類に記載されている事項は下記の出願書類に記載されて  
いる事項と同一であることを証明する。

This is to certify that the annexed is a true copy of the following application as filed  
with this Office

出願年月日

Date of Application:

2001年 3月27日

出願番号

Application Number:

特願2001-091275

[ST.10/C]:

[JP2001-091275]

出願人

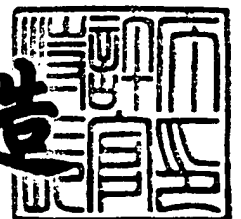
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2002年 2月 8日

特許庁長官  
Commissioner,  
Japan Patent Office

及川耕造



出証番号 出証特2002-3005634